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With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



### Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China







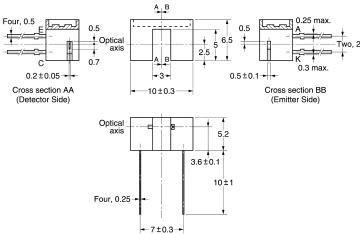
#### OMRON

# **EE-SX1082**

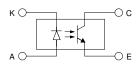
### **Photomicrosensor** (Transmissive)

#### ■ Dimensions

Note: All units are in millimeters unless otherwise indicated.



#### **Internal Circuit**



Unless otherwise specified, the tolerances are ±0.2 mm.

Terminal No.	Name
Α	Anode
K	Cathode
С	Collector
E	Emitter

#### ■ Features

- Horizontal sensing aperture.
- PCB mounting type.
- High resolution with a 0.2-mm-wide aperture.

#### **Absolute Maximum Ratings** $(Ta = 25^{\circ}C)$

Item		Symbol	Rated value
Emitter	Forward current	IF	50 mA (see note 1)
	Pulse forward current	I <sub>FP</sub>	1 A (see note 2)
	Reverse voltage	$V_R$	4 V
Detector	Collector-Emitter voltage	$V_{CEO}$	30 V
	Emitter-Collector voltage	V <sub>ECO</sub>	
	Collector current	I <sub>C</sub>	20 mA
	Collector dissipation	P <sub>C</sub>	100 mW (see note 1)
Ambient temperature	Operating	Topr	–40°C to 85°C
	Storage	Tstg	–40°C to 100°C
Soldering temperature		Tsol	260°C (see note 3)

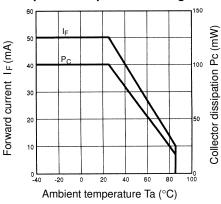
- Note: 1. Refer to the temperature rating chart if the ambient temperature exceeds 25°C.
  - 2. The pulse width is 10  $\mu s$  maximum with a frequency of 100 Hz.
  - 3. Complete soldering within 10 seconds.

### ■ Electrical and Optical Characteristics (Ta = 25°C)

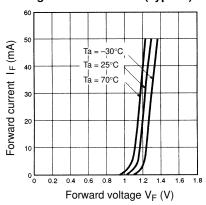
	Item	Symbol	Value	Condition
Emitter	Forward voltage	V <sub>F</sub>	1.2 V typ., 1.5 V max.	I <sub>F</sub> = 30 mA
	Reverse current	I <sub>R</sub>	0.01 μA typ., 10 μA max.	V <sub>R</sub> = 4 V
	Peak emission wavelength	λ <sub>P</sub>	920 nm typ.	I <sub>F</sub> = 20 mA
Detector	Light current	IL	0.12 mA min.	I <sub>F</sub> = 20 mA, V <sub>CE</sub> = 5 V
	Dark current	I <sub>D</sub>	2 nA typ., 200 nA max.	V <sub>CE</sub> = 10 V, 0 ℓx
	Leakage current	I <sub>LEAK</sub>		
	Collector–Emitter saturated voltage	V <sub>CE</sub> (sat)	0.08 V typ., 0.4 V max.	$I_F = 20 \text{ mA}, I_L = 0.05 \text{ mA}$
	Peak spectral sensitivity wavelength	λР	850 nm typ.	V <sub>CE</sub> = 10 V
Rising tim	ie	tr	100 μs typ.	$V_{CC} = 5 \text{ V}, R_L = 50 \text{ k}\Omega, I_L = 0.1 \text{ mA}$
Falling tin	ne	tf	1,000 μs typ.	$V_{CC} = 5 \text{ V}, R_L = 50 \text{ k}\Omega, I_L = 0.1 \text{ mA}$

#### **■** Engineering Data

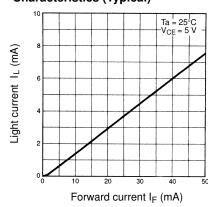
## Forward Current vs. Collector Dissipation Temperature Rating



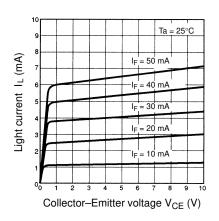
Forward Current vs. Forward Voltage Characteristics (Typical)



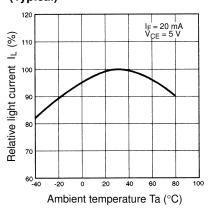
Light Current vs. Forward Current Characteristics (Typical)



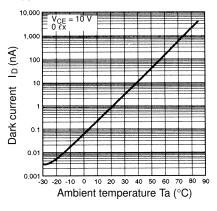
Light Current vs. Collector–Emitter Voltage Characteristics (Typical)



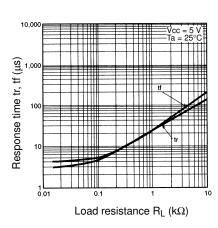
Relative Light Current vs. Ambient Temperature Characteristics (Typical)



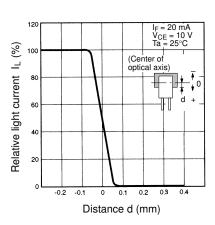
Dark Current vs. Ambient Temperature Characteristics (Typical)



Response Time vs. Load Resistance Characteristics (Typical)



**Sensing Position Characteristics** (Typical)



Response Time Measurement Circuit

